

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74AC161P, TC74AC161F, TC74AC161FN, TC74AC161FT

TC74AC163P, TC74AC163F, TC74AC163FN, TC74AC163FT

SYNCHRONOUS PRESETTABLE 4 – BIT BINARY COUNTER

TC74AC161P/F/FN/FT ASYNCHRONOUS CLEAR

TC74AC163P/F/FN/FT SYNCHRONOUS CLEAR

The TC74AC161 and 163 are advanced high speed CMOS SYNCHRONOUS PRESETTABLE COUNTERS fabricated with silicon gate and double - layer metal wiring C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The CK input is active on the rising edge. Both $\overline{\text{LOAD}}$ and $\overline{\text{CLR}}$ inputs are active on low logic level.

Presetting of these IC's is synchronous to the rising edge of CK.

The clear function of the TC74AC163 is synchronous to CK, while the TC74AC161 are cleared asynchronously.

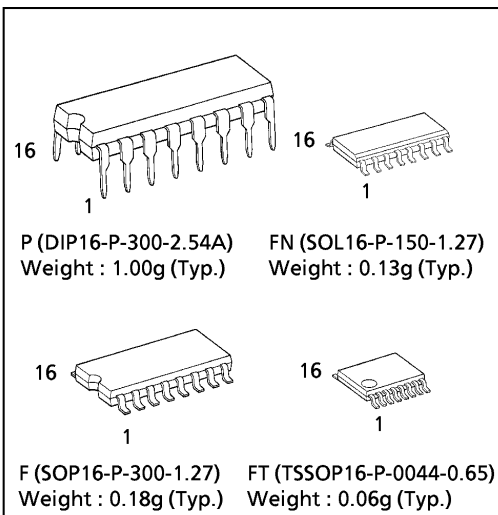
Two enable inputs (ENP and ENT) and CARRY OUTPUT are provided to enable easy cascading of counters, which facilitates easy implementation of n - bit counters without using external gates.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

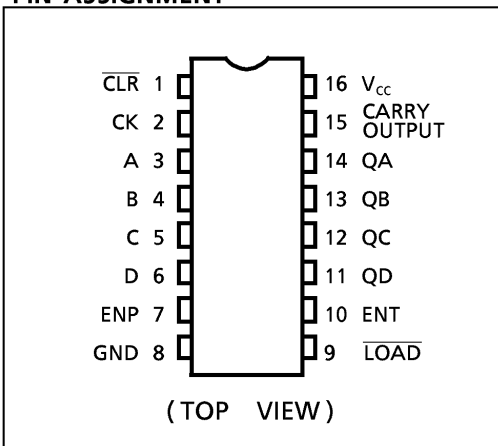
FEATURES:

- High Speed..... $f_{\text{MAX}} = 170\text{MHz}(\text{typ.})$ at $V_{\text{CC}} = 5\text{V}$
- Low Power Dissipation..... $I_{\text{CC}} = 8\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}(\text{Min.})$
- Symmetrical Output Impedance... $|I_{\text{OH}}| = |I_{\text{OL}}| = 24\text{mA}(\text{Min.})$
Capability of driving 50Ω transmission lines.
- Balanced Propagation Delays..... $t_{\text{PLH}} \approx t_{\text{PHL}}$
- Wide Operating Voltage Range... $V_{\text{CC}}(\text{opr}) = 2\text{V} \sim 5.5\text{V}$
- Pin and Function Compatible with 74F161/163

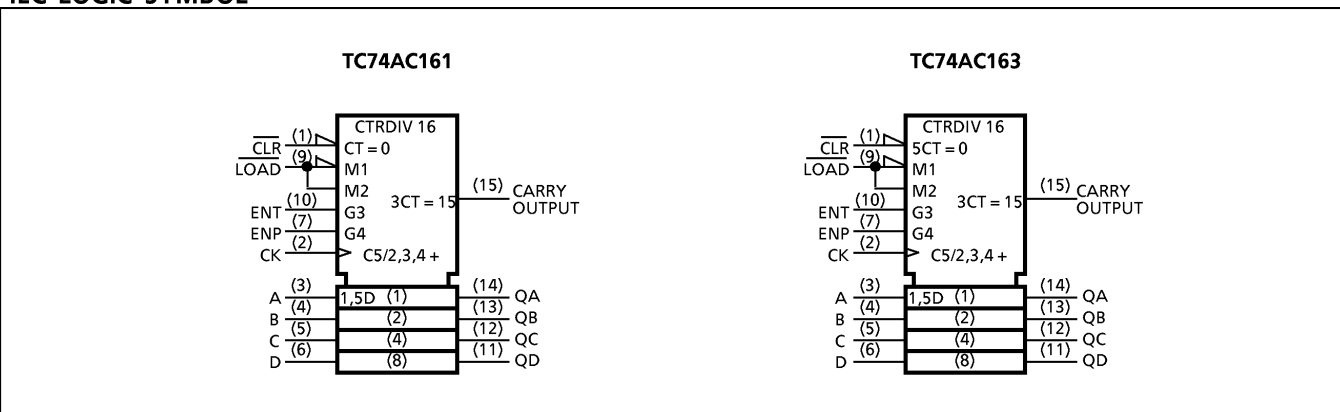
(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT



IEC LOGIC SYMBOL



961001EBA2

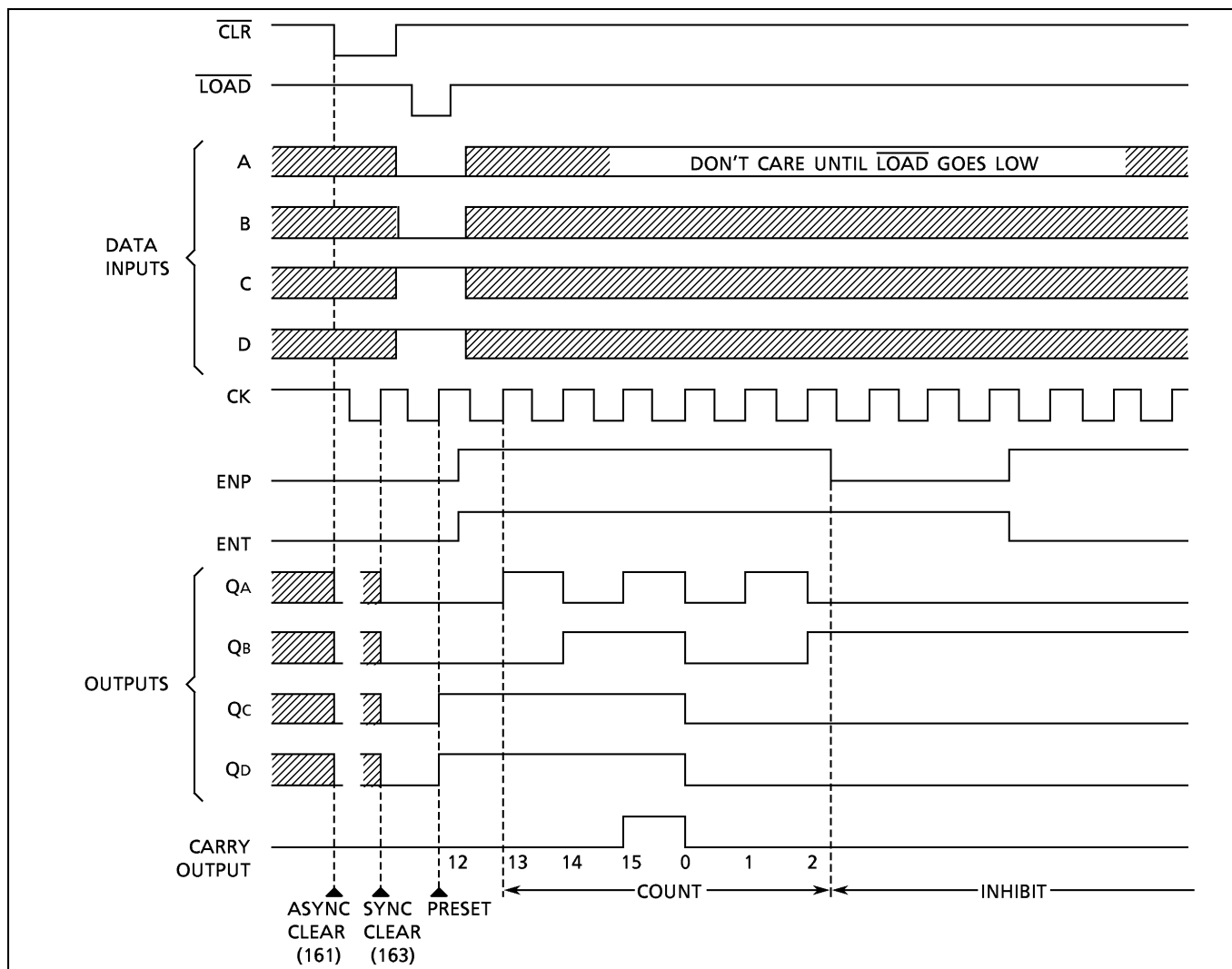
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TRUTH TABLE

INPUTS							OUTPUTS				FUNCTION
$\overline{\text{CLR}}$ (161)	$\overline{\text{CLR}}$ (163)	$\overline{\text{LOAD}}$	ENP	ENT	CK (161)	CK (163)	QA	QB	QC	QD	
L	L	X	X	X	X	$\uparrow$	L	L	L	L	RESET TO "0"
H	H	L	X	X	$\uparrow$	$\uparrow$	A	B	C	D	PRESET DATA
H	H	H	X	L	$\uparrow$	$\uparrow$	NO CHANGE				NO COUNT
H	H	H	L	X	$\uparrow$	$\uparrow$	NO CHANGE				NO COUNT
H	H	H	H	H	$\uparrow$	$\uparrow$	COUNT UP				COUNT
H	X	X	X	X	$\downarrow$	$\downarrow$	NO CHANGE				NO COUNT

Note X : Don't Care
 A, B, C, D : Logic Level of Data Inputs
 Carry : $\text{CARRY} = \text{ENT} \cdot \text{QA} \cdot \text{QB} \cdot \text{QC} \cdot \text{QD}$

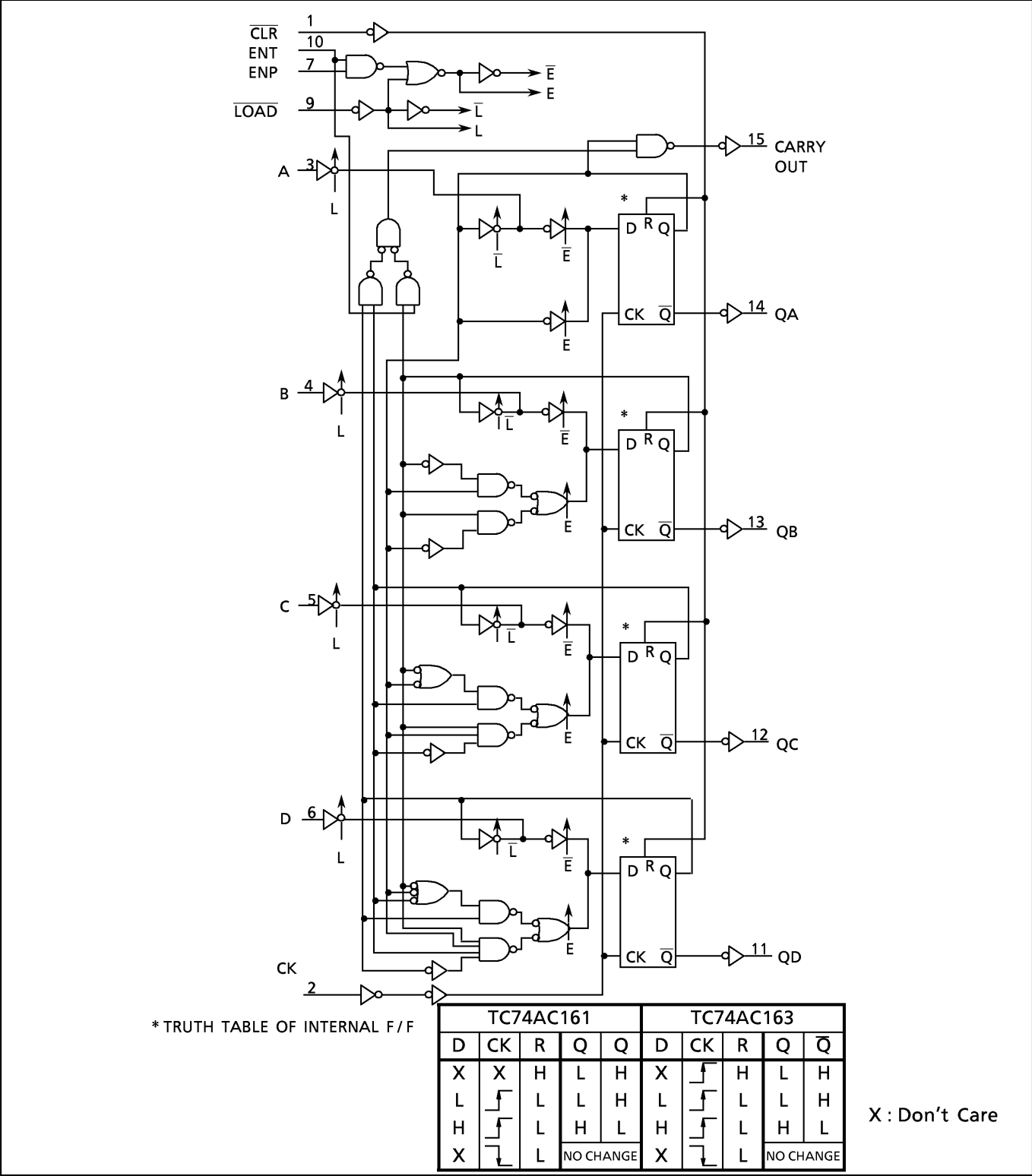
TIMING CHART



961001EBA2'

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SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 7.0$	V
DC Input Voltage	V_{IN}	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 50	mA
DC Output Current	I_{OUT}	± 50	mA
DC V_{CC} /Ground Current	I_{CC}	± 125	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP/TSSOP)	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	°C

*500mW in the range of $T_a = -40^\circ\text{C} \sim 65^\circ\text{C}$. From $T_a = 65^\circ\text{C}$ to 85°C a derating factor of $-10\text{mW}/^\circ\text{C}$ should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	$2.0 \sim 5.5$	V
Input Voltage	V_{IN}	$0 \sim V_{CC}$	V
Output Voltage	V_{OUT}	$0 \sim V_{CC}$	V
Operating Temperature	T_{opr}	$-40 \sim 85$	°C
Input Rise and Fall Time	dt/dV	$0 \sim 100$ ($V_{CC} = 3.3 \pm 0.3\text{V}$) $0 \sim 20$ ($V_{CC} = 5 \pm 0.5\text{V}$)	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \sim 85^\circ\text{C}$		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}		2.0 3.0 5.5	1.50 2.10 3.85	— — —	— — —	1.50 2.10 3.85	— — —	V
Low - Level Input Voltage	V_{IL}		2.0 3.0 5.5	— — —	— — —	0.50 0.90 1.65	— — —	0.50 0.90 1.65	V
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -50\mu\text{A}$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	V
			$I_{OH} = -4\text{mA}$	3.0	2.58	—	—	2.48	
			$I_{OH} = -24\text{mA}$	4.5	3.94	—	—	3.80	
			$I_{OH} = -75\text{mA}^*$	5.5	—	—	—	3.85	
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 50\mu\text{A}$	2.0 3.0 4.5	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	V
			$I_{OL} = 12\text{mA}$	3.0	—	—	0.36	—	
			$I_{OL} = 24\text{mA}$	4.5	—	—	0.36	—	
			$I_{OL} = 75\text{mA}^*$	5.5	—	—	—	1.65	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC} \text{ or GND}$	5.5	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC} \text{ or GND}$	5.5	—	—	8.0	—	80.0	

* : This spec indicates the capability of driving 50Ω transmission lines.

One output should be tested at a time for a 10ms maximum duration.

TIMING REQUIREMENTS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C		Ta = -40~85°C	UNIT
			V _{CC} (V)	LIMIT		
Minimum Pulse Width (CK)	$t_{W(L)}$ $t_{W(H)}$	Fig .1	3.3 ± 0.3 5.0 ± 0.5	7.0 5.0	7.0 5.0	ns
Minimum Pulse Width ($\overline{\text{CLR}}$)*	$t_{W(L)}$	Fig .4	3.3 ± 0.3 5.0 ± 0.5	7.0 5.0	7.0 5.0	
Minimum Set - up Time (LOAD, ENP, ENT)	t_s	Fig .2, 3	3.3 ± 0.3 5.0 ± 0.5	11.0 7.0	13.0 7.0	
Minimum Set - up Time (A, B, C, D)	t_s	Fig .2	3.3 ± 0.3 5.0 ± 0.5	8.0 4.0	8.0 4.0	
Minimum Set - up Time ($\overline{\text{CLR}}$)**	t_s	Fig .5	3.3 ± 0.3 5.0 ± 0.5	6.0 4.0	6.0 4.0	
Minimum Hold Time	t_h	Fig .2, 3, 5	3.3 ± 0.3 5.0 ± 0.5	1.0 1.0	1.0 1.0	
Minimum Removal Time ($\overline{\text{CLR}}$)*	t_{rem}	Fig .4	3.3 ± 0.3 5.0 ± 0.5	6.0 4.0	6.0 4.0	

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, R_L = 500 Ω, Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = − 40~85°C		UNIT
			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (CK—Q)	t _{pLH} t _{pHL}	Fig.1	3.3 ± 0.3 5.0 ± 0.5	— —	8.8 6.5	15.8 9.6	1.0 1.0	18.0 11.0	ns
Propagation Delay Time (CK—CARRY, Count Mode)	t _{pLH} t _{pHL}	Fig.1	3.3 ± 0.3 5.0 ± 0.5	— —	10.4 8.1	18.4 11.8	1.0 1.0	21.0 13.5	
Propagation Delay Time (CK—CARRY, Preset Mode)	t _{pLH} t _{pHL}	Fig.2	3.3 ± 0.3 5.0 ± 0.5	— —	12.9 9.1	22.4 13.2	1.0 1.0	25.5 15.0	
Propagation Delay Time (ENT—CARRY)	t _{pLH} t _{pHL}	Fig.6	3.3 ± 0.3 5.0 ± 0.5	— —	7.5 5.8	13.2 8.3	1.0 1.0	15.0 9.5	
Propagation Delay Time ($\overline{\text{CLR}}$ —Q)*	t _{pHL}	Fig.4	3.3 ± 0.3 5.0 ± 0.5	— —	10.6 7.7	18.4 11.4	1.0 1.0	21.0 13.0	
Propagation Delay Time ($\overline{\text{CLR}}$ —CARRY)*	t _{pHL}	Fig.4	3.3 ± 0.3 5.0 ± 0.5	— —	12.0 8.6	21.0 12.7	1.0 1.0	24.0 14.5	
Maximum Clock Frequency	f _{MAX}		3.3 ± 0.3 5.0 ± 0.5	50 90	110 140	— —	50 90	— —	MHz
Input Capacitance	C _{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C _{PD} (1)			—	85	—	—	—	

Note * for TC74AC161 only

** for TC74AC163 only

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

When the outputs drive a capacitive load, total current consumption is the sum of C_{PD} , and ΔI_{CC} which is obtained from the following formula :

$$\Delta I_{CC} = f_{CK} \cdot V_{CC} \left(\frac{C_{QA}}{2} + \frac{C_{QB}}{4} + \frac{C_{QC}}{8} + \frac{C_{QD}}{16} + \frac{C_{CO}}{16} \right)$$

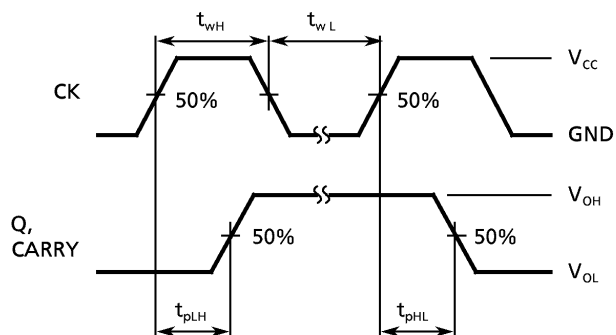
$C_{QA} \sim C_{QD}$ and C_{CO} are the capacitances at QA~QD and CARRY OUT, respectively.

f_{CK} is the input frequency of the CK.

SWITCHING CHARACTERISTICS TEST WAVEFORM

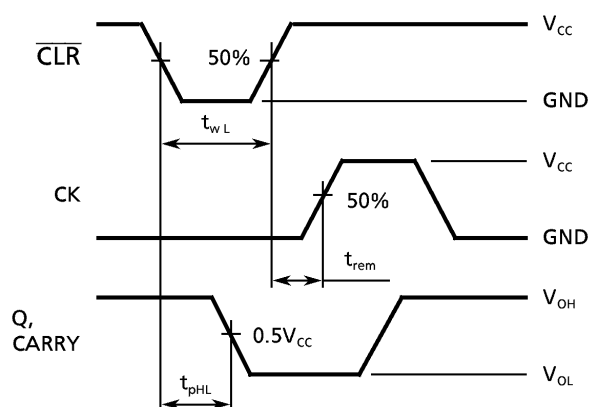
COUNT MODE

(Fig. 1)



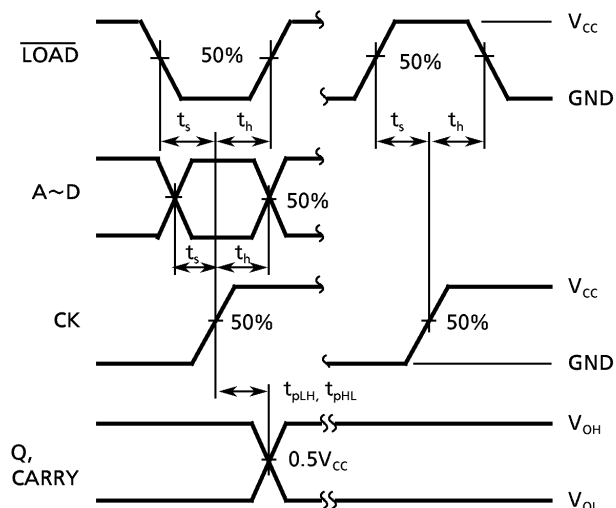
CLEAR MODE (TC74AC161)

(Fig. 4)



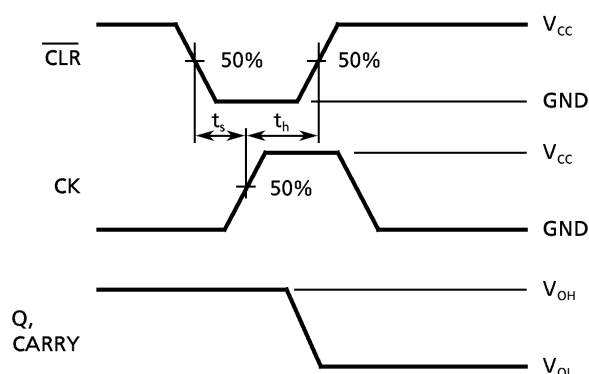
PRESET MODE

(Fig. 2)



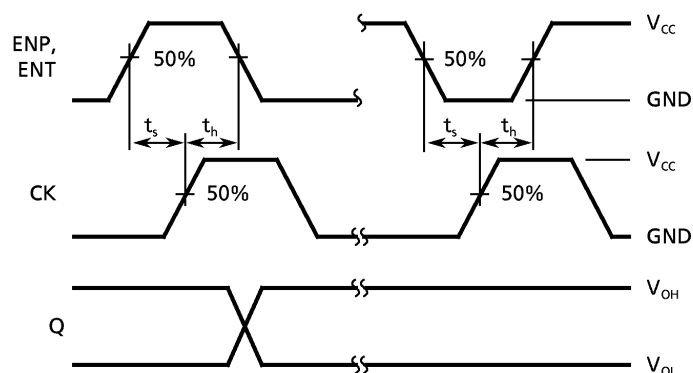
CLEAR MODE (TC74AC163)

(Fig. 5)

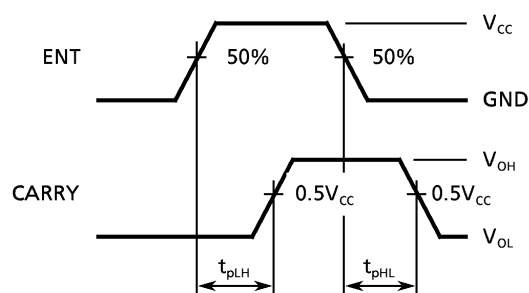


COUNT ENABLE MODE

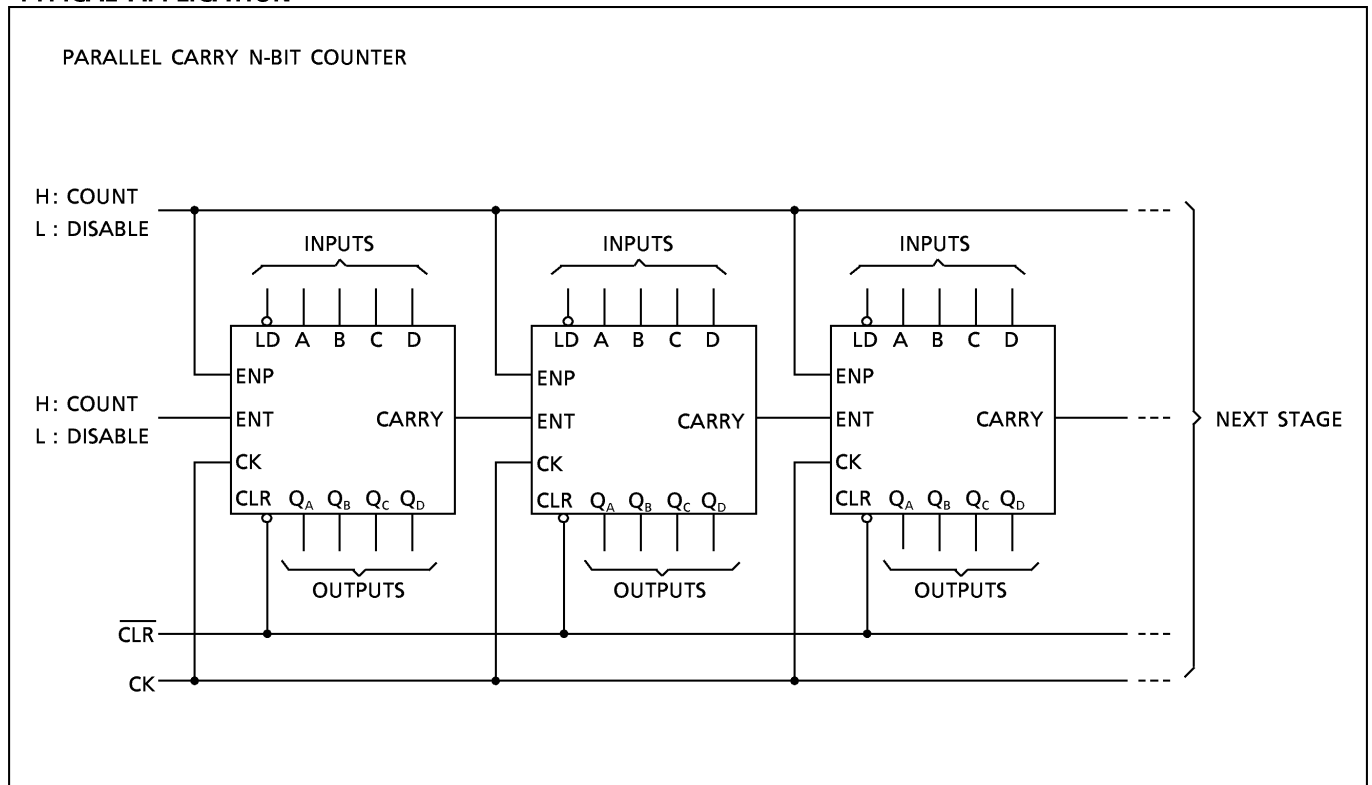
(Fig. 3)

CASCADE MODE
(Fix Maximum Count)

(Fig. 6)

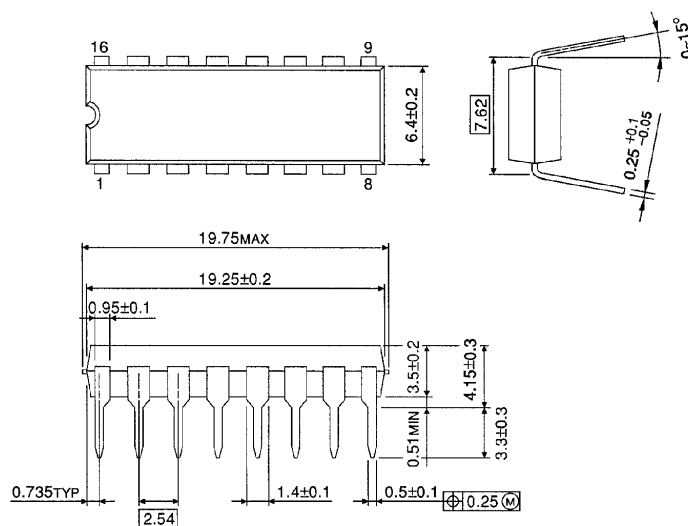


TYPICAL APPLICATION



DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)

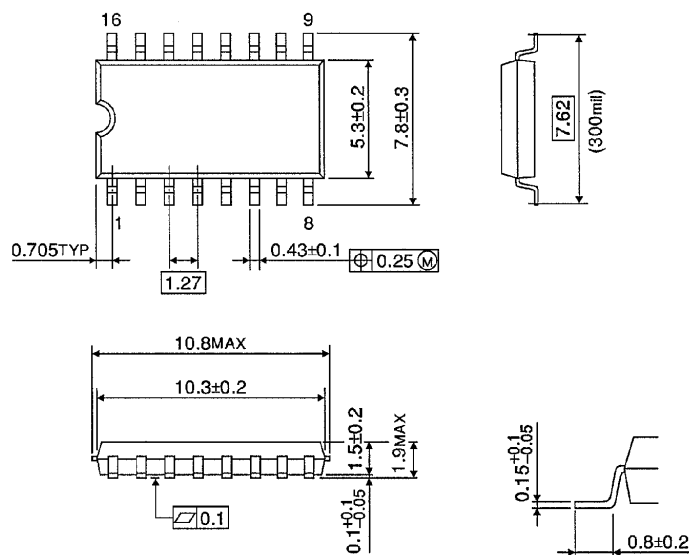
Unit in mm



Weight : 1.00g (Typ.)

SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)

Unit in mm

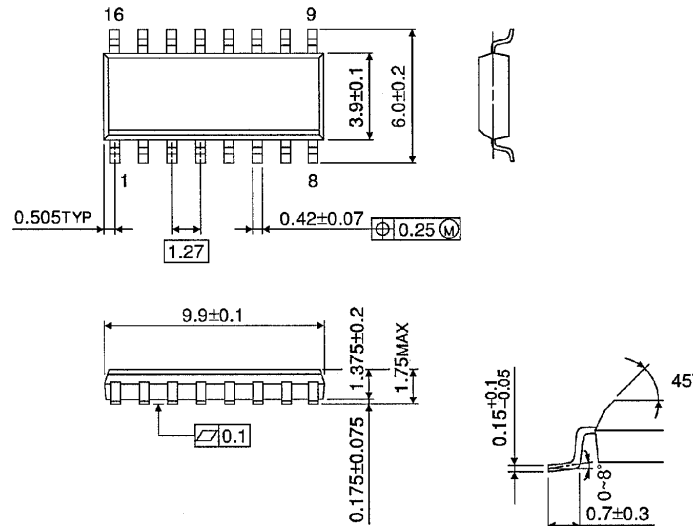


Weight : 0.18g (Typ.)

SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150 -1.27)

Unit in mm

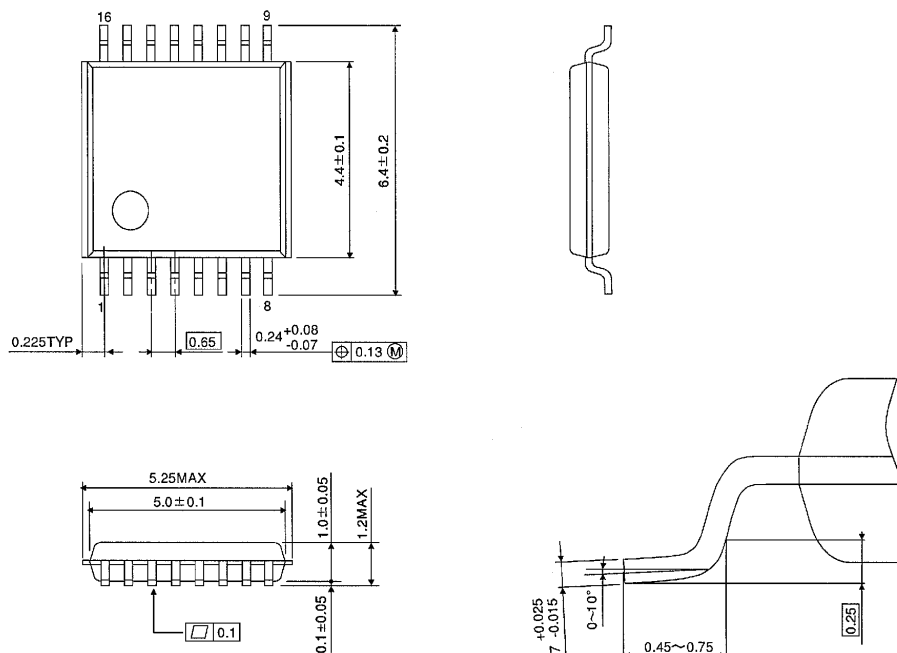
(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)

TSSOP 16PIN OUTLINE DRAWING (TSSOP16-P-0044-0.65)

Unit in mm



Weight : 0.06g (Typ.)